

# MC74HC03A

## Quad 2-Input NAND Gate with Open-Drain Outputs High-Performance Silicon-Gate CMOS

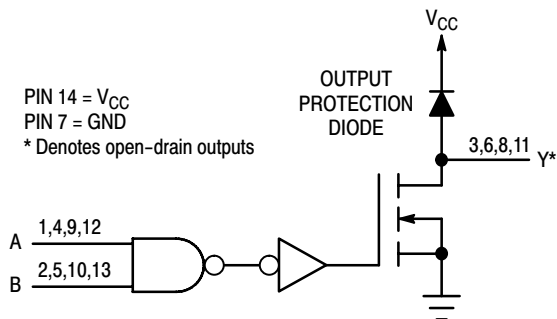
The MC74HC03A is identical in pinout to the LS03. The device inputs are compatible with Standard CMOS outputs; with pullup resistors, they are compatible with LSTTL outputs.

The HC03A NAND gate has, as its outputs, a high-performance MOS N-Channel transistor. This NAND gate can, therefore, with a suitable pullup resistor, be used in wired-AND applications. Having the output characteristic curves given in this data sheet, this device can be used as an LED driver or in any other application that only requires a sinking current.

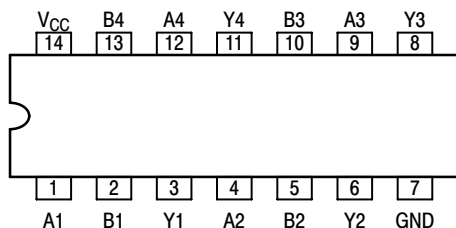
### Features

- Output Drive Capability: 10 LSTTL Loads With Suitable Pullup Resistor
- Outputs Directly Interface to CMOS, NMOS and TTL
- High Noise Immunity Characteristic of CMOS Devices
- Operating Voltage Range: 2.0 to 6.0 V
- Low Input Current: 1µA
- In Compliance With the JEDEC Standard No. 7A Requirements
- Chip Complexity: 28 FETs or 7 Equivalent Gates
- Pb-Free Packages are Available

### LOGIC DIAGRAM



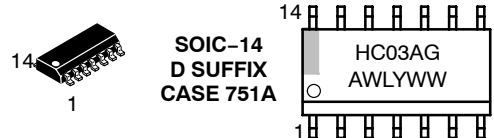
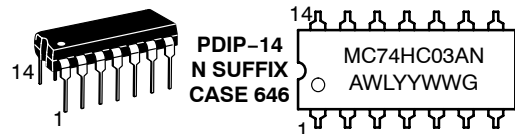
### Pinout: 14-Lead Packages (Top View)



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### MARKING DIAGRAMS



A = Assembly Location  
 WL or L = Wafer Lot  
 YY or Y = Year  
 WW or W = Work Week  
 G or ■ = Pb-Free Package

(Note: Microdot may be in either location)

### FUNCTION TABLE

| Inputs |   | Output |
|--------|---|--------|
| A      | B | Y      |
| L      | L | Z      |
| L      | H | Z      |
| H      | L | Z      |
| H      | H | L      |

Z = High Impedance

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

# MC74HC03A

## MAXIMUM RATINGS

| Symbol    | Parameter   | Value   | Unit              |    |
|-----------|---|---|-------------------|----|
| $V_{CC}$  | DC Supply Voltage (Referenced to GND)   | - 0.5 to + 7.0                                  | V                 |    |
| $V_{in}$  | DC Input Voltage (Referenced to GND)  | - 0.5 to $V_{CC} + 0.5$                         | V                 |    |
| $V_{out}$ | DC Output Voltage (Referenced to GND)   | - 0.5 to $V_{CC} + 0.5$                         | V                 |    |
| $I_{in}$  | DC Input Current, per Pin   | $\pm 20$  | mA                |    |
| $I_{out}$ | DC Output Current, per Pin  | $\pm 25$  | mA                |    |
| $I_{CC}$  | DC Supply Current, $V_{CC}$ and GND Pins  | $\pm 50$  | mA                |    |
| $P_D$     | Power Dissipation in Still Air  | Plastic DIP†<br>SOIC Package†<br>TSSOP Package† | 750<br>500<br>450 | mW |
| $T_{stg}$ | Storage Temperature   | - 65 to + 150                                   | °C                |    |
| $T_L$     | Lead Temperature, 1 mm from Case for 10 Seconds<br>Plastic DIP, SOIC or TSSOP Package | 260   | °C                |    |

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation,  $V_{in}$  and  $V_{out}$  should be constrained to the range  $GND \leq (V_{in} \text{ or } V_{out}) \leq V_{CC}$ . Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or  $V_{CC}$ ). Unused outputs must be left open.

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

†Derating — Plastic DIP: - 10 mW/°C from 65° to 125°C  
SOIC Package: - 7 mW/°C from 65° to 125°C  
TSSOP Package: - 6.1 mW/°C from 65° to 125°C

For high frequency or heavy load considerations, see Chapter 2 of the ON Semiconductor High-Speed CMOS Data Book (DL129/D).

## RECOMMENDED OPERATING CONDITIONS

| Symbol            | Parameter  | Min  | Max         | Unit               |    |
|-------------------|--|--|-------------|--------------------|----|
| $V_{CC}$          | DC Supply Voltage (Referenced to GND)                | 2.0  | 6.0         | V                  |    |
| $V_{in}, V_{out}$ | DC Input Voltage, Output Voltage (Referenced to GND) | 0  | $V_{CC}$    | V                  |    |
| $T_A$             | Operating Temperature, All Package Types             | - 55   | + 125       | °C                 |    |
| $t_r, t_f$        | Input Rise and Fall Time<br>(Figure 1)               | $V_{CC} = 2.0 \text{ V}$<br>$V_{CC} = 4.5 \text{ V}$<br>$V_{CC} = 6.0 \text{ V}$ | 0<br>0<br>0 | 1000<br>500<br>400 | ns |

## DESIGN GUIDE

| Criteria                        | Value  | Unit          |
|---------------------------------|--------|---------------|
| Internal Gate Count*            | 7.0    | ea            |
| Internal Gate Propagation Delay | 1.5    | ns            |
| Internal Gate Power Dissipation | 5.0    | $\mu\text{W}$ |
| Speed Power Product             | 0.0075 | pJ            |

\*Equivalent to a two-input NAND gate

# MC74HC03A

## ORDERING INFORMATION

| Device         | Package                | Shipping <sup>†</sup> |
|----------------|------------------------|-----------------------|
| MC74HC03AN     | PDIP-14                | 25 Units/Rail         |
| MC74HC03ANG    | PDIP-14<br>(Pb-Free)   |                       |
| MC74HC03AD     | SOIC-14                | 55 Units/Rail         |
| MC74HC03ADG    | SOIC-14<br>(Pb-Free)   |                       |
| MC74HC03ADR2   | SOIC-14                | 2500/Tape & Reel      |
| MC74HC03ADR2G  | SOIC-14<br>(Pb-Free)   |                       |
| MC74HC03ADTR2  | TSSOP-14*              |                       |
| MC74HC03ADTR2G | TSSOP-14*              |                       |
| MC74HC03AFEL   | SOEIAJ-14              | 2000/Tape & Reel      |
| MC74HC03AFELG  | SOEIAJ-14<br>(Pb-Free) |                       |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*This package is inherently Pb-Free.

# MC74HC03A

## DC CHARACTERISTICS (Voltages Referenced to GND)

| Symbol          | Parameter                                      | Condition   | V <sub>CC</sub><br>V | Guaranteed Limit |       |        | Unit |
|-----------------|--|---|----------------------|------------------|-------|--------|------|
|                 |  |   |                      | -55 to 25°C      | ≤85°C | ≤125°C |      |
| V <sub>IH</sub> | Minimum High-Level Input Voltage               | V <sub>out</sub> = 0.1V or V <sub>CC</sub> - 0.1V<br> I <sub>out</sub>   ≤ 20μA   | 2.0                  | 1.50             | 1.50  | 1.50   | V    |
|                 |  |   | 3.0                  | 2.10             | 2.10  | 2.10   |      |
|                 |  |   | 4.5                  | 3.15             | 3.15  | 3.15   |      |
|                 |  |   | 6.0                  | 4.20             | 4.20  | 4.20   |      |
| V <sub>IL</sub> | Maximum Low-Level Input Voltage                | V <sub>out</sub> = 0.1V or V <sub>CC</sub> - 0.1V<br> I <sub>out</sub>   ≤ 20μA   | 2.0                  | 0.50             | 0.50  | 0.50   | V    |
|                 |  |   | 3.0                  | 0.90             | 0.90  | 0.90   |      |
|                 |  |   | 4.5                  | 1.35             | 1.35  | 1.35   |      |
|                 |  |   | 6.0                  | 1.80             | 1.80  | 1.80   |      |
| V <sub>OL</sub> | Maximum Low-Level Output Voltage               | V <sub>out</sub> = 0.1V or V <sub>CC</sub> - 0.1V<br> I <sub>out</sub>   ≤ 20μA   | 2.0                  | 0.1              | 0.1   | 0.1    | V    |
|                 |  |   | 4.5                  | 0.1              | 0.1   | 0.1    |      |
|                 |  |   | 6.0                  | 0.1              | 0.1   | 0.1    |      |
|                 |  | V <sub>in</sub> = V <sub>IH</sub> or V <sub>IL</sub><br> I <sub>out</sub>   ≤ 2.4mA<br> I <sub>out</sub>   ≤ 4.0mA<br> I <sub>out</sub>   ≤ 5.2mA | 3.0                  | 0.26             | 0.33  | 0.40   |      |
|                 |  |   | 4.5                  | 0.26             | 0.33  | 0.40   |      |
|                 |  |   | 6.0                  | 0.26             | 0.33  | 0.40   |      |
| I <sub>in</sub> | Maximum Input Leakage Current                  | V <sub>in</sub> = V <sub>CC</sub> or GND  | 6.0                  | ±0.1             | ±1.0  | ±1.0   | μA   |
| I <sub>CC</sub> | Maximum Quiescent Supply Current (per Package) | V <sub>in</sub> = V <sub>CC</sub> or GND<br>I <sub>out</sub> = 0μA  | 6.0                  | 1.0              | 10    | 40     | μA   |
| I <sub>OZ</sub> | Maximum Three-State Leakage Current            | Output in High-Impedance State<br>V <sub>in</sub> = V <sub>IL</sub> or V <sub>IH</sub><br>V <sub>out</sub> = V <sub>CC</sub> or GND               | 6.0                  | ±0.5             | ±5.0  | ±10    | μA   |

NOTE: Information on typical parametric values can be found in Chapter 2 of the ON Semiconductor High-Speed CMOS Data Book (DL129/D).

## AC CHARACTERISTICS (C<sub>L</sub> = 50pF, Input t<sub>r</sub> = t<sub>f</sub> = 6ns)

| Symbol                                 | Parameter  | V <sub>CC</sub><br>V | Guaranteed Limit |       |        | Unit |
|--|--|----------------------|------------------|-------|--------|------|
|  |  |                      | -55 to 25°C      | ≤85°C | ≤125°C |      |
| t <sub>PLZ</sub> ,<br>t <sub>PZL</sub> | Maximum Propagation Delay, Input A or B to Output Y<br>(Figures 1 and 2)   | 2.0                  | 120              | 150   | 180    | ns   |
|  |  | 3.0                  | 45               | 60    | 75     |      |
|  |  | 4.5                  | 24               | 30    | 36     |      |
|  |  | 6.0                  | 20               | 26    | 31     |      |
| t <sub>TLH</sub> ,<br>t <sub>THL</sub> | Maximum Output Transition Time, Any Output<br>(Figures 1 and 2)            | 2.0                  | 75               | 95    | 110    | ns   |
|  |  | 3.0                  | 27               | 32    | 36     |      |
|  |  | 4.5                  | 15               | 19    | 22     |      |
|  |  | 6.0                  | 13               | 16    | 19     |      |
| C <sub>in</sub>                        | Maximum Input Capacitance  |                      | 10               | 10    | 10     | pF   |
| C <sub>out</sub>                       | Maximum Three-State Output Capacitance<br>(Output in High-Impedance State) |                      | 10               | 10    | 10     | pF   |

NOTE: For propagation delays with loads other than 50 pF, and information on typical parametric values, see Chapter 2 of the ON Semiconductor High-Speed CMOS Data Book (DL129/D).

| C <sub>PD</sub> | Power Dissipation Capacitance (Per Buffer)* | Typical @ 25°C, V <sub>CC</sub> = 5.0 V, V <sub>EE</sub> = 0 V |  | pF |
|-----------------|---|--|--|----|
|                 |   | 8.0  |  |    |
|                 |   |  |  |    |

\* Used to determine the no-load dynamic power consumption: P<sub>D</sub> = C<sub>PD</sub> V<sub>CC</sub><sup>2</sup>f + I<sub>CC</sub> V<sub>CC</sub>. For load considerations, see Chapter 2 of the ON Semiconductor High-Speed CMOS Data Book (DL129/D).

# MC74HC03A

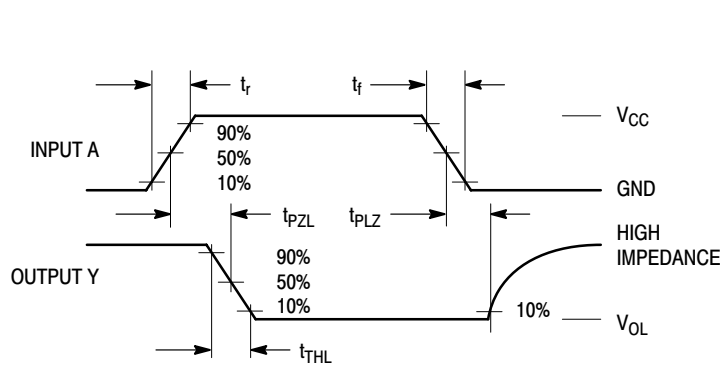


Figure 1. Switching Waveforms

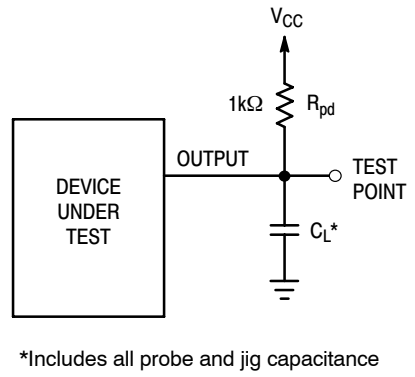
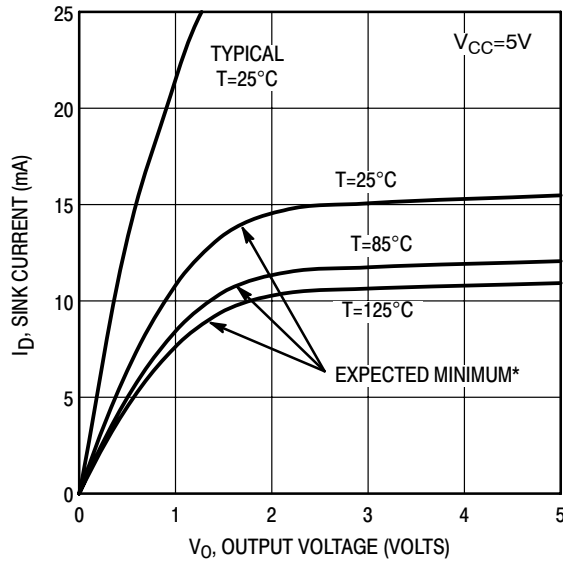


Figure 2. Test Circuit



\*The expected minimum curves are not guarantees, but are design aids.

Figure 3. Open-Drain Output Characteristics

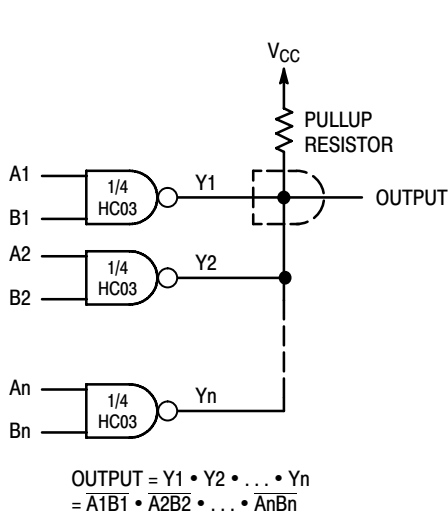


Figure 4. Wired AND

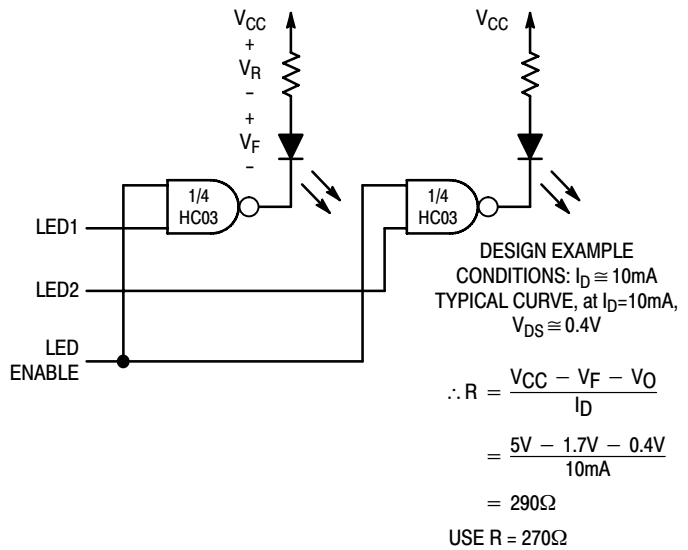
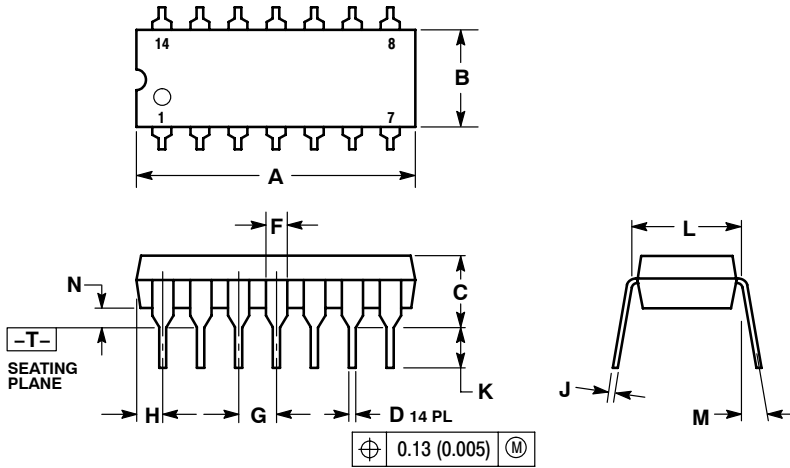


Figure 5. LED Driver With Blanking

# MC74HC03A

## PACKAGE DIMENSIONS

**PDIP-14**  
CASE 646-06  
ISSUE P



**NOTES:**

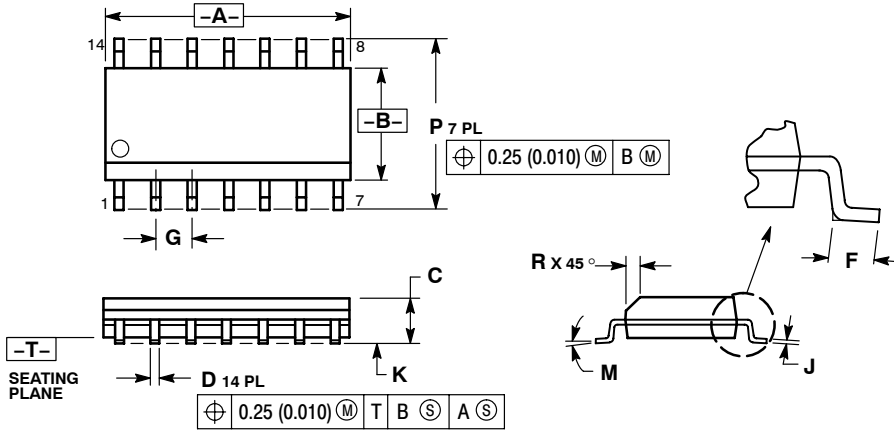
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.

| DIM | INCHES    |       | MILLIMETERS |       |
|-----|-----------|-------|-------------|-------|
|     | MIN       | MAX   | MIN         | MAX   |
| A   | 0.715     | 0.770 | 18.16       | 19.56 |
| B   | 0.240     | 0.260 | 6.10        | 6.60  |
| C   | 0.145     | 0.185 | 3.69        | 4.69  |
| D   | 0.015     | 0.021 | 0.38        | 0.53  |
| F   | 0.040     | 0.070 | 1.02        | 1.78  |
| G   | 0.100 BSC |       | 2.54 BSC    |       |
| H   | 0.052     | 0.095 | 1.32        | 2.41  |
| J   | 0.008     | 0.015 | 0.20        | 0.38  |
| K   | 0.115     | 0.135 | 2.92        | 3.43  |
| L   | 0.290     | 0.310 | 7.37        | 7.87  |
| M   | ---       | 10°   | ---         | 10°   |
| N   | 0.015     | 0.039 | 0.38        | 1.01  |

# MC74HC03A

## PACKAGE DIMENSIONS

SOIC-14  
CASE 751A-03  
ISSUE H

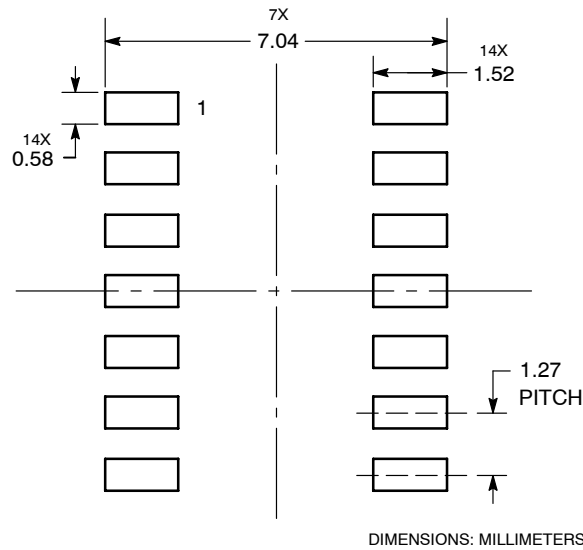


### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

| MILLIMETERS |          | INCHES |           |       |
|-------------|----------|--------|-----------|-------|
| DIM         | MIN      | MAX    | MIN       | MAX   |
| A           | 8.55     | 8.75   | 0.337     | 0.344 |
| B           | 3.80     | 4.00   | 0.150     | 0.157 |
| C           | 1.35     | 1.75   | 0.054     | 0.068 |
| D           | 0.35     | 0.49   | 0.014     | 0.019 |
| F           | 0.40     | 1.25   | 0.016     | 0.049 |
| G           | 1.27 BSC |        | 0.050 BSC |       |
| J           | 0.19     | 0.25   | 0.008     | 0.009 |
| K           | 0.10     | 0.25   | 0.004     | 0.009 |
| M           | 0°       | 7°     | 0°        | 7°    |
| P           | 5.80     | 6.20   | 0.228     | 0.244 |
| R           | 0.25     | 0.50   | 0.010     | 0.019 |

### SOLDERING FOOTPRINT\*

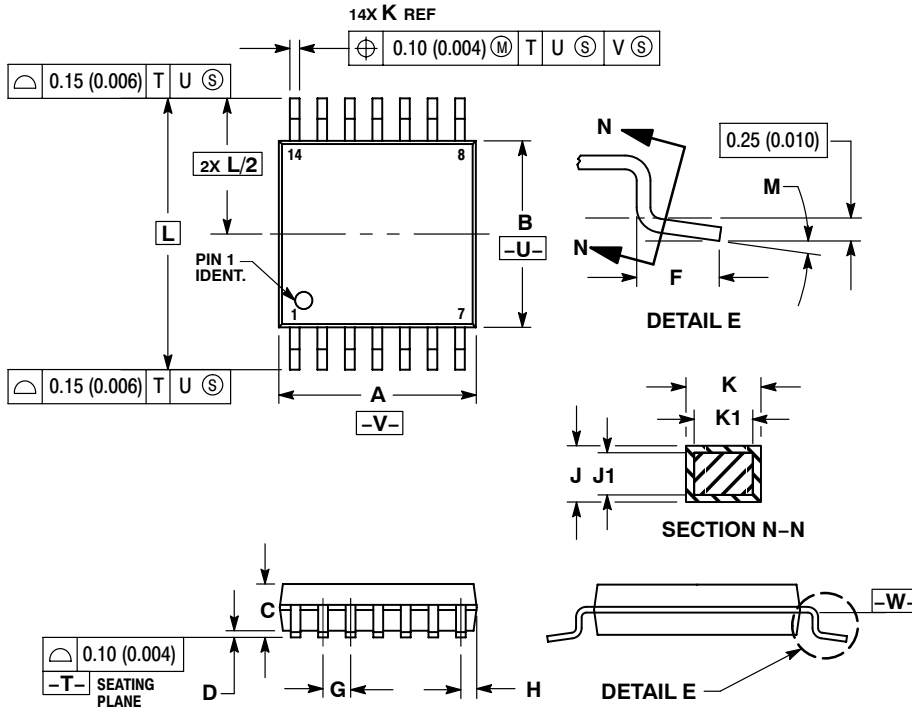


\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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## PACKAGE DIMENSIONS

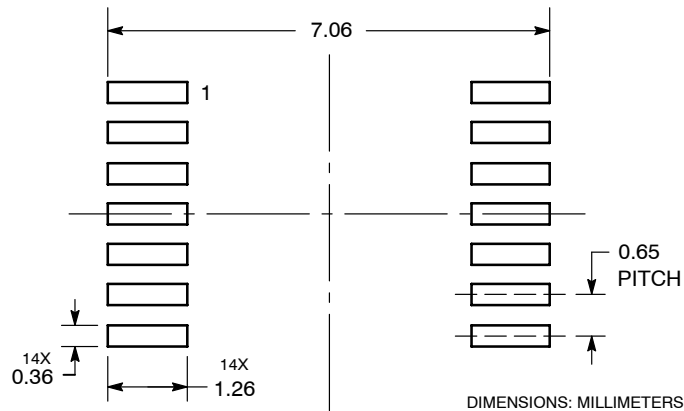
TSSOP-14  
CASE 948G-01  
ISSUE B



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
  4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
  5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
  6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
  7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

| DIM | MILLIMETERS |      | INCHES    |       |
|-----|-------------|------|-----------|-------|
|     | MIN         | MAX  | MIN       | MAX   |
| A   | 4.90        | 5.10 | 0.193     | 0.200 |
| B   | 4.30        | 4.50 | 0.169     | 0.177 |
| C   | ---         | 1.20 | ---       | 0.047 |
| D   | 0.05        | 0.15 | 0.002     | 0.006 |
| F   | 0.50        | 0.75 | 0.020     | 0.030 |
| G   | 0.65 BSC    |      | 0.026 BSC |       |
| H   | 0.50        | 0.60 | 0.020     | 0.024 |
| J   | 0.09        | 0.20 | 0.004     | 0.008 |
| J1  | 0.09        | 0.16 | 0.004     | 0.006 |
| K   | 0.19        | 0.30 | 0.007     | 0.012 |
| K1  | 0.19        | 0.25 | 0.007     | 0.010 |
| L   | 6.40 BSC    |      | 0.252 BSC |       |
| M   | 0°          | 8°   | 0°        | 8°    |

### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



# MC74HC03A

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